© 1993 IEEE. Personal use of this material is permitted. However, permission to reprint/republish this material for advertising or promotional purposes or for creating new collective works for resale or redistribution to servers or lists, or to reuse any copyrighted component of this work in other works must be obtained from the IEEE.

A New Formulation of Longitudinal Coherent Instabilities

S.Y. Zhang and W.T. Weng

AGS Department, Brookhaven National Laboratory Upton, New York 11973

Abstract - The quadrature response of longitudinal impedance is shown to be the effective impedance for the beam instability. The results of the application of this formulation are compared with that obtained using the Robinson-Pedersen approach and the Sacherer integral equation. The formulation is further generalized to the rigid bunch motion using signal analysis method, where a form factor shows up naturally. Finally, the formulation is applied to solve the coupled bunch instabilities. Examples of the AGS Booster and the AGS coupled bunch instabilities are used to illustrate the applications of the formulation.

I. The New Formulation

In the longitudinal motion, a synchrotron oscillation is modulated by the RF carrier. The beam current induced voltage through the longitudinal impedance may affect the synchrotron oscillation and cause the beam instability.

A. Beam Dynamic Model

A beam dynamic model is shown in Fig.1, where s is the Laplace operator, ω_O and ω_{RF} are the revolution and RF frequencies, respectively. ΔV_B is the equivalent RF gap voltage deviation caused by the beam motion, and ΔV_{CAV} caused by the cavity voltage variation. I_B is the beam current amplitude of the fundamental frequency, i.e., the RF frequency. Finally, $Z_M(s)$ represents the effective longitudinal impedance with respect to the beam instability. In the block diagram, the upper loop represents the synchrotron oscillation, as shown in [1]. The lower loop represents the effects of the beam current to the cavity voltage through the longitudinal impedance.



Fig.1. Beam Dynamic Model

B. Impedance

We use both Laplace and Fourier transforms. For instance, an impedance in the Laplace form can be $Z(s+j\omega_{RF})$, and its counterpart in the Fourier form is written as $Z(\omega+\omega_{RF})$. Consider a general situation of the modulated input and output. Let the input signal of a system be f(t) and the output be g(t). The input signal is assumed to be a low frequency signal $f_L(t)$ modulated by an RF carrier, say $\cos\omega_{RF} t$, i.e., we can write, $f(t) = f_L(t) \cos\omega_{RF} t$. Using $f(t) \rightarrow F(\omega)$ and $f_L(t) \rightarrow F_L(\omega)$ to denote the Fourier pairs, we have,

$$F(\omega) = \frac{1}{2} \left(F_L(\omega + \omega_{RF}) + F_L(\omega - \omega_{RF}) \right)$$
(1)

Also for $f_1(t) = f_L(t) \sin \omega_{RF} t$, we have,

$$F_1(\omega) = \frac{1}{2j} \left(F_L(\omega + \omega_{RF}) - F_L(\omega - \omega_{RF}) \right)$$
(2)

Under the modulation of the frequency ω_{RF} , the inphase and quadrature responses of the impedance $Z(\omega)$ are determined by [2],

$$Z_P(\omega) = \frac{1}{2} \left(Z(\omega + \omega_{RF}) + Z(\omega - \omega_{RF}) \right) , \qquad (3)$$

$$Z_{Q}(\omega) = \frac{1}{2j} \left(Z(\omega + \omega_{RF}) - Z(\omega - \omega_{RF}) \right)$$
(4)

respectively. We also define $G_P(\omega) = F_L(\omega)Z_P(\omega)$ and $G_Q(\omega) = F_L(\omega)Z_Q(\omega)$. Using $g_P(t) \rightarrow G_P(\omega)$ and $g_Q(t) \rightarrow G_Q(\omega)$ for Fourier pairs, the total response of the modulated signal $F(\omega)$ in (1) through the impedance $Z(\omega)$ is,

$$g(t) = g_P(t) \cos \omega_{RF} t + g_Q(t) \sin \omega_{RF} t \qquad (5)$$

Using (1-4), the equation (5) can be shown to be,

$$G(\omega) = F(\omega)Z(\omega)) \tag{6}$$

therefore (5) is proved. When the beam passes the cavity gap, the in-phase response due to the cavity impedance, which is modulated by $\cos \omega_{RF} t$, provides an almost constant force in the beam synchrotron oscillation, which has little effect on the beam instability. On the other hand, since the quadrature response is modulated by $\sin \omega_{RF} t$ it is in the same fashion as that of the RF driving wave and functions as the same as the RF driving wave. Therefore, if the instability of synchrotron oscillation is concerned, the quadrature response represented by (4) becomes a dominant effect. Thus the effective longitudinal impedance is,

$$Z_{M}(s) = Z_{Q}(s) = \frac{1}{2j} \left(Z(s+j\omega_{RF}) - Z(s-j\omega_{RF}) \right)$$
(7)

Consider an RF cavity with the resonant frequency ω_R , the shunt resistance R, the halfbandwidth σ , and the quality factor Q. Under the conditions of Q >> 1, $\omega_{RF} \approx \omega_R >> \omega \approx \omega_S$, and also $|\omega_R^2 - \omega_{RF}^2| >> |s^2| = \omega^2$, the longitudinal impedance of the RF cavity is,

$$Z_M(s) = \frac{-R\sigma^2 \tan \phi_Z}{s^2 + 2\sigma s + \sigma^2 (1 + \tan^2 \phi_Z)}$$
(8)

where the detuning angle $\phi_Z = \tan^{-1} \left((\omega_{RF} - \omega_R) / \sigma \right)$. C. Stability

To study the beam stability under the influence of the longitudinal impedance of RF cavity, we can write the following equation from Fig.1,

$$\phi = \frac{e\,\omega_O\,\omega_{RF}\,\eta\,V\cos\phi_S}{2\pi\beta^2 E\,s^2}\phi + \frac{e\,\omega_O\,\omega_{RF}\,\eta}{2\pi\beta^2 E\,s^2}\,Z_M(s)I_B\phi \quad (9)$$

^{*} Work performed under the auspices of the U.S. Department of Energy

Using $\omega_S^2 = -e \omega_O \omega_{RF} \eta V \cos \phi_S / (2\pi \beta^2 E)$ and the beam and generator current ratio $Y = I_B / I_{G0} = I_B R / V$, the characteristic equation of the system becomes,

$$s^{2} + \omega_{S}^{2} = \frac{\omega_{S}^{2} Y \sigma^{2} \tan \phi_{Z} / \cos \phi_{S}}{s^{2} + 2\sigma s + \sigma^{2} (1 + \tan^{2} \phi_{Z})}$$
(10)

Using Routh-Hurwitz table, it is straightforward to find the stability conditions as $\tan \phi_Z > 0$ and $Y \tan \phi_Z \cos^2 \phi_Z < \cos \phi_S$, which are called the first and second Robinson criteria, respectively.

In deriving the transfer function $Z_M(s)$ in Fig.1, the in-phase and quadrature transfer functions $Z_P(s)$ and $Z_Q(s)$ are used. In the Robinson - Pedersen approach [3], the beam to cavity phase and amplitude transmissions and their cross transmissions $Z_{pp}(s)$, $Z_{aa}(s)$, and $Z_{pa}(s)$, $Z_{ap}(s)$ are used to derive the total equivalent transmission from the beam phase variation to the induced cavity voltage phase deviation. In Fig.2, typical step responses of the transfer functions are plotted, which show the difference between the two types of the transfer functions, and the two approaches as well.



Fig.2. Step Responses for the Transfer Functions.

Using Sacherer integral equation [4] for the dipole motion, we get the following equation,

$$s^{2} + \omega_{S}^{2} = \frac{8\pi\omega_{S}^{2}I_{0}}{V\cos\phi_{S}} \left(\int_{0}^{\infty} J_{1}^{2}(r) \frac{d\psi_{0}}{dr} dr\right) Z_{M}(s)$$
(11)

where I_0 is the beam average current, ψ_0 is the bunch stationary distribution, and r is the amplitude of the beam phase oscillation. Substituting (8), the equation (11) is shown to be equivalent to (10), except for a scaling difference.

II. Generalize the Formulation

To generalize the formulation to the rigid bunch motion, the beam current signal needs to be analyzed. For each frequency component in the signal, the corresponding effective impedance can be found, which needs only a trivial modification from the results shown in Section I. The summation of the effects of the impedance due to each component in the signal is the force the beam received.

A. Signal of rigid bunch motion

Let T_{RF} be the RF period, $T_{RF}=2\pi/\omega_{RF}$, a beam longitudinal current signal with N particles in a bunch is,

$$i(t) = N e \sum_{k=-\infty}^{\infty} \delta \left(t - kT_{RF} + \tau \cos \omega_S k T_{RF} \right) \quad (12)$$

where τ is the synchrotron oscillation amplitude in time. The spectrum of this signal is calculated as [1],

$$I(\omega) = 2\pi I_0 \sum_{p,m=-\infty}^{\infty} j^m J_m(\omega\tau) \,\delta\left(\omega - p\,\omega_{RF} - m\,\omega_S\right) \,(13)$$

We further assume that the bunches have a Gaussian distribution, which is chosen for convenience, and with an effective bunch length τ_L . Using the phase oscillation amplitude $r = \omega_{RF} \tau$ the equation (13) becomes [1],

$$I(\omega) = 2\pi I_0 \sum_{p,m=-\infty}^{\infty} j^m J_m(r\omega/\omega_{RF})$$
$$\times e^{-(\tau_L \omega/\omega_{RF})^2/32} \delta(\omega - p \omega_{RF} - m \omega_S)$$
(14)

B. Generalization

To compare the rigid bunch signal represented by (14) with the idealized signal, we may write the signal used to develop the formulation in Section I as $i_1(t) = I_B r \cos \omega_S t \sin \omega_{RF} t$, whose spectrum is,

$$I_1(\omega) = 2\pi I_B \frac{r}{4j} \sum_{p,m=\pm 1} (-p) \,\delta\left(\omega - p \,\omega_{RF} - m \,\omega_S\right) \quad (15)$$

The first difference between the real rigid bunch motion signal represented by (14) and the idealized signal (15) is that (14) contains not only RF frequency modulation but also RF harmonics modulation, i.e., by the frequencies $p \omega_{RF}$, |p| > 1. It is shown [1] that $Z_M(\omega) = Z_Q(\omega)$ is valid not only for the RF frequency modulation, but also for the RF harmonic modulation. For the carrier with the frequency $p \omega_{RF}$, the variable ω_{RF} in (4) should however be replaced by $p \omega_{RF}$. In the system synthesis, firstly these frequency components in the rigid bunch motion signal should be identified, then the corresponding longitudinal impedances should be used to find the induced forces. The combined force is the one the beam received.

The second difference of (14) from (15) is that it contains not only dipole motion but also high mode motion, i.e., $m \omega_S$, |m| > 1.

The third difference is that in (14), the spectrum amplitude is affected by the Bessel function, the bunch distribution and the bunch length. The combined influence of these factors can be called a form factor. C. Form factor

Consider the most important case of dipole motion with RF frequency modulation, where $p = \pm 1$ and $m = \pm 1$. We write (14) as,

$$I(\omega) = 8\pi I_0 J_1(r |\omega| / \omega_{RF}) e^{-(r_L \omega / \omega_{RF})^2 / 32}$$
$$\times \frac{1}{4j} \sum_{p,m=\pm 1} (-p) \,\delta \left(\omega - p \,\omega_{RF} - m \,\omega_S\right) \tag{16}$$

For the delta distribution, $I_B = 2I_0$, the form factor can be written as,

$$F = \frac{I(\omega)}{I_1(\omega)} = \frac{2J_1(r \mid \omega \mid /\omega_{RF})}{r} e^{-(r_L \omega / \omega_{RF})^2/32}$$
$$\approx \frac{2J_1(r)}{r} e^{-(r_L \omega / \omega_{RF})^2/32}$$
(17)

where in the simplification we used $|\omega| \approx \omega_{RF}$.

Consider the longitudinal dipole motion discussed in Section I again. The form factor F in (17) has to be multiplied to the scaling I_B in Fig.1, and therefore also to $Y = I_B R / V$ in (10). Thus, $Y_1 = FY$ will replace Y in the second stability equation. Since F < 1, the stability margin is extended.

III. Coupled Bunch Instabilities

A. Coupled bunch motion

Let there be h bunches, and let n be the coupled bunch mode number. There will be n = 0, 1, ..., h-1coupled bunch modes [4]. The spectrum of the signal observed from the wall monitor becomes,

$$I(\omega) = 2\pi I_0 \sum_{p,m=-\infty}^{\infty} j^m J_m(r\omega/\omega_{RF})$$
$$\times e^{-(r_L \omega/\omega_{RF})^2/32} \delta(\omega - p \omega_{RF} - n \omega_0 - m \omega_S) \quad (18)$$

The coupled bunch mode of $n \omega_0$ can be assumed to be a rigid wave. For an individual bunch, the modulation effect of the beam current signal due to the coupled bunch mode is demodulated. By the same argument as in Section I, the quadrature response represents the effective longitudinal impedance. Therefore we have the following longitudinal impedance,

$$Z_M(\omega) = \frac{1}{2j} \left(Z(\omega + n \,\omega_0 + \omega_{RF}) - Z(\omega + n \,\omega_0 - \omega_{RF}) \right) \, (19)$$

B. Coupled bunch instabilities

If $n \neq 0$, then the two spectrum lines of the same frequency modulation may be far apart, therefore in general the treatment for the resonator type impedance such as that in Section I cannot be applied, and the spectrum lines may have to be treated separately. Consider the dipole upper sideband at $Z(\omega+\omega_0+\omega_{RF})$ in (19), and let the real part of the impedance be R_1 . Using $s = j\omega \approx j\omega_S$, the stability equation can be written as,

$$s^{2} + \omega_{S}^{2} = \frac{\omega_{S}^{2} I_{B} F}{2 j V \cos \phi_{S}} Z(\omega + \omega_{0} + \omega_{RF}) \approx \frac{-\omega_{S} I_{B} F R_{1}}{2 V \cos \phi_{S}} s (20)$$

Below transition $\cos\phi_S > 0$, therefore the upper sideband is stable because that the coefficient of s is negative. It follows that the lower sideband at $Z(\omega+\omega_0-\omega_{RF})$, which has a negative sign in (19), is unstable, and the opposite above transition.

It is interesting to revisit the form factor derived in Section II. We rewrite it as,

$$F = \frac{2J_{1}(r |\omega|/\omega_{RF})}{r} e^{-(r_{L}\omega/\omega_{RF})^{2}/32}$$
(21)

The simplification of the form factor in (17) cannot be made in the case of the coupled bunch mode, since now $|\omega|$ is not close to ω_{RF} if $n \neq 0$, and both variables have to be considered in the Bessel function. For high frequency, the influence of r shows up, which is shown in Fig.3.



Fig.3. Form Factors with Different r.

In a small range of r, for instance between 0.01 to 0.2 in Fig.3, the form factors are approximately the same. This shows the reason why we can assume that the coupled bunch mode is a rigid wave in the instability study.

C. Examples of the AGS Booster and the AGS

A coupled bunch instability has been excited in the AGS booster by tuning a test RF cavity [5]. In the booster h is 3, and f_{RF} was 2.55 MHz. In the test, the coupled bunch instability of a dipole mode was observed at the first revolution line, i.e., at 850 KHz, which implies that n = 2. We have $I_0 = 0.082$ A, $\phi_S = 0$, and V = 30 KV, and $\tau_L = 130$ nS. The RF cavity used to excite the coupled bunch motion has approximately a quality factor 2.5 and a shunt resistance 3 K Ω , it was tuned at the revolution frequency in the test. To estimate the effective resistance FR_1 , the form factor in (21) is used, where the Gaussian distribution is still used allowing minor errors. The effective resistance of the test cavity is found to be 1 K Ω at 850 KHz. The growth rate calculated using (20) is 27.7 mS, which is close to the test result of 30 mS.

In an AGS operation, a coupled bunch instability was observed at the 1.77 GeV front porch, with $f_{RF} = 4.18$ MHz, and n = 11 (h = 12). To find the location of frequency of the exciting resonator, two tests were performed, with τ_L are 46 nS and 70 nS, I_0 are 0.089 A and 0.457 A, V are 260 KV and 184 KV, and f_S are 1.64 KHz and 1.38 KHz, respectively. The observed growth rates are 48 mS and 24 mS, respectively. Using a moderate $r = 0.1r_L$, the resistance required to generate the observed growth rates are plotted in Fig.4, which shows that at 17.6 MHz the required resistances are crossed. The closest unstable coupled bunch mode frequency is at 17.1 MHz, therefore Fig.4 shows a possible location of the exciting resonator. This result agrees to the one obtained by different approaches [6].



Fig.4. Resistances to Excite the Growth Rates.

Acknowledgment

The authors would like to thank A. Chao, E.C. Raka, and A.M. Sessler for helpful discussions.

References

- S.Y. Zhang and W.T. Weng, BNL Informal Report, No.48905, May, 1993.
- [2] A. Paupolis, 'The Fourier Integral and Its Applications,' New York, McGraw-Hill, 1962.
- [3] F. Pedersen, IEEE Trans. NS-22, 1906, 1975.
- [4] F. Sacherer, IEEE Trans. NS-24, 1393, 1977.
- [5] M. Blaskiewicz, Private communication.
- [6] E.C. Raka, Private communication.